

# EGP10A - EGP10K

## 1.0 Ampere Glass Passivated High Efficiency Rectifiers

### Features

- Superfast recovery time for high efficiency
- Low forward voltage, high current capability
- Low leakage current
- High surge current capability



**DO-41 Glass case**  
COLOR BAND DENOTES CATHODE

### Absolute Maximum Ratings\* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
I <sub>O</sub>	Average Rectified Current .375" lead length @ T <sub>L</sub> = 75°C	1.0	A
I <sub>r(surge)</sub>	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	30	A
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	2.5 17	W mW°C
l <sub>C</sub>	Thermal Resistance, Junction to Ambient	50	°C/W
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature Range	-65 ~ 150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

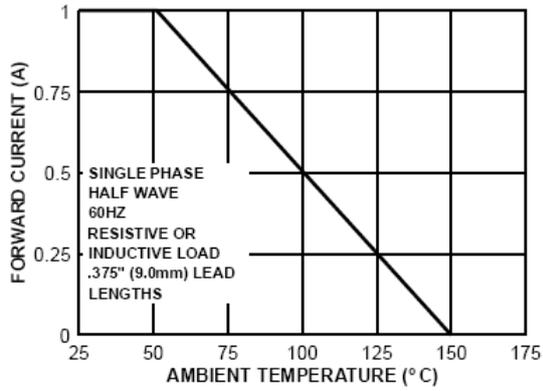
### Electrical Characteristics\* T<sub>a</sub> = 25°C unless otherwise noted

Parameter	Device								Units
	10A	10B	10C	10D	10F	10G	10J	10K	
Peak Repetitive Reverse Voltage	50	100	150	200	300	400	600	800	V
Maximum RMS Voltage	35	70	105	140	210	280	420	560	V
DC Reverse Voltage (Rated V <sub>R</sub> )	50	100	150	200	300	400	600	800	V
Maximum Reverse Current @ rated V <sub>R</sub> T <sub>A</sub> = 25°C T <sub>A</sub> = 125°C	5.0 100								μA μA
Maximum Reverse Recovery Time I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A	50						75		nS
Maximum Forward Voltage @ 1.0 A	0.95			1.25		1.7			V
Typical Junction Capacitance V <sub>R</sub> = 4.0 V, f = 1.0 MHz	22				15				pF

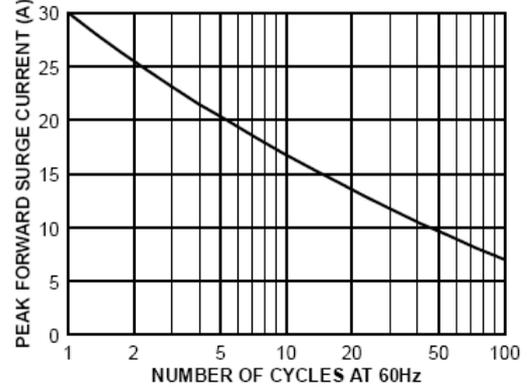
\* Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%

## Typical Performance Characteristics

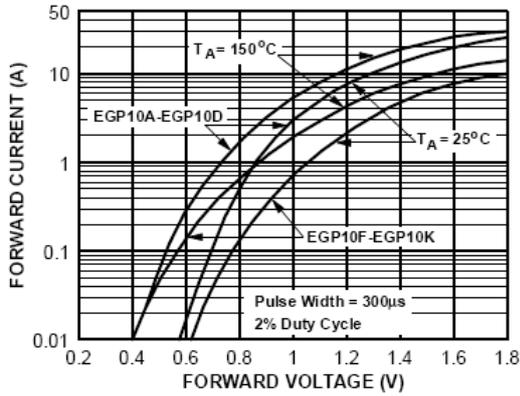
### Forward Current Derating Curve



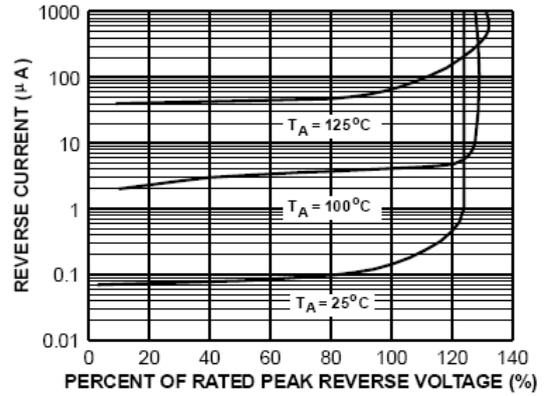
### Non-Repetitive Surge Current



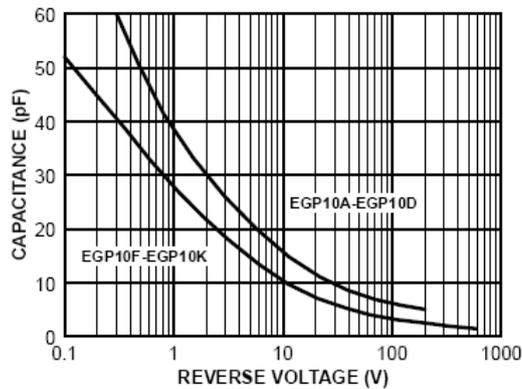
### Forward Characteristics



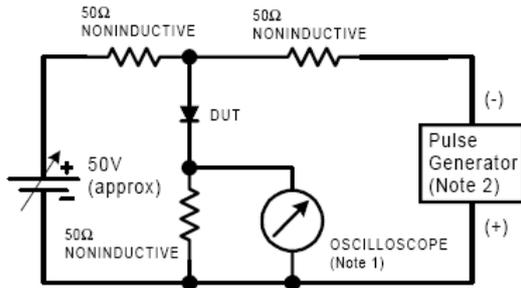
### Reverse Characteristics



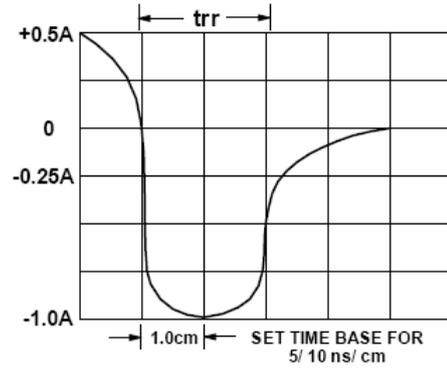
### Junction Capacitance



### Reverse Recovery Time Characteristic and Test Circuit Diagram



- NOTES:
1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf.
  2. Rise time = 10 ns max; Source impedance = 50 ohms.





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